Preliminary

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT6L54S

VHF-UHF Band Low Noise Amplifier Application VHF-UHF Band Oscillator Application

• Two devices are built into the sES6 package, which is smaller and thinner than the super-thin and ultra-super-mini (6-pin) ES6 package.

Mounted Devices

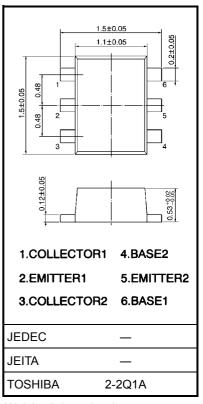
	Q1: SSM (TESM)	Q2: TESM
Three-pin (SSM/TESM) product No.	MT3S06S (MT3S06T)	MT3S08T

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Q1	Q2	Unit		
Collector-base voltage	V_{CBO}	10	20	V		
Collector-emitter voltage	V _{CEO}	5	8	V		
Emitter-base voltage	V _{EBO}	1.5	1.5	V		
Collector current	IC	15	15 40			
Base current	ΙΒ	7	10	mA		
Collector power dissipation	P _C (Note 1)	150		150		mW
Junction temperature	Tj	125		125		°C
Storage temperature range	T _{stg}	-55~125		-55~125		°C

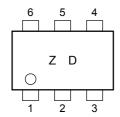
Note 1: Total power dissipation of Q1 and Q2 mounted on the circuit board

Unit: mm

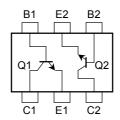


Weight: 2.1 mg (typ.)

Marking



Pin Connections



Electrical Characteristics Q1-Side (Ta = 25°C)

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Characteristics	Symbol	Test Condition		Min	Тур.	Max	Unit	
Collector cut-off current	I _{CBO}	$V_{CB} = 5 \text{ V}, I_{E} = 0$		_	_	0.1	μΑ	
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 \text{ V}, I_C = 0$		_	_	1	μΑ	
DC current gain	h _{FE}	V _{CE} = 1 V, I _C = 5 mA		70		140	_	
Transition frequency	f _T	$V_{CE} = 3 \text{ V}, I_{C} = 5 \text{ mA}$		7	10	_	GHz	
Insertion gain	S _{21e} ² (1)	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$		_	7.5	_	dB	
	S _{21e} ² (2)	$V_{CE} = 3 \text{ V}, I_{C} = 7 \text{ mA}, f = 2 \text{ GHz}$		4.5	8.3	_		
Noise figure	NF (1)	$V_{CE} = 1 \text{ V}, I_{C} = 3 \text{ mA}, f = 2 \text{ GHz}$		_	1.7	3	dB	
	NF (2)	$V_{CE} = 3 \text{ V}, I_{C} = 3 \text{ mA}, f = 2 \text{ GHz}$		_	1.6	3	uБ	
Reverse transfer capacitance	C _{re}	$V_{CB} = 1 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ (Note	2)	_	0.35	0.75	pF	

Electrical Characteristics Q2-Side (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 \text{ V, } I_C = 0$	_	_	1	μΑ
DC current gain	h _{FE}	$V_{CE} = 1 \text{ V, } I_{C} = 5 \text{ mA}$	80	_	140	_
Transition frequency	f _T	$V_{CE} = 1 \text{ V, } I_{C} = 5 \text{ mA}$	2	4.5	_	GHz
Insertion gain	S _{21e} ² (1)	$V_{CE} = 1 \text{ V, } I_{C} = 5 \text{ mA, } f = 1 \text{ GHz}$	_	9.5	_	dB
	S _{21e} ² (2)	$V_{CE} = 3 \text{ V}, I_{C} = 20 \text{ mA}, f = 1 \text{ GHz}$	9.5	12.5	_	ub
Noise figure	NF	$V_{CE} = 1 \text{ V, } I_{C} = 5 \text{ mA, } f = 1 \text{ GHz}$	_	1.4	2.5	dB
Reverse transfer capacitance	C _{re}	$V_{CB} = 1 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$ (Note 2)		0.55	0.95	pF

Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

2

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